

AM / FM - PLL

Description

The U4289BM is an integrated circuit in BICMOS technology for frequency synthesizers. It performs all the functions of a PLL radio tuning system and is controlled

by an I^2C bus. The device is designed for all frequency synthesizer applications in radio receivers, as well as RDS (**R**adio **D**ata **S**ystem) applications.

Features

- Reference oscillator up to 15 MHz
- Two programmable 16 bit dividers adjustable from 2 to 65535
- High signal/noise ratio

• Fine tuning steps:

 $AM \ge 1 \text{ kHz}$ $FM \ge 2 \text{ kHz}$

• Few external component required due to integrated loop-push-pull stage for AM/FM

Ordering Information

Extended Type Number	Package	Remarks			
U4289BM-MFP	SO16 plastic				
U4289BM-MFPG3	SO16 plastic	Taping according to IEC-286-3			

Block Diagram

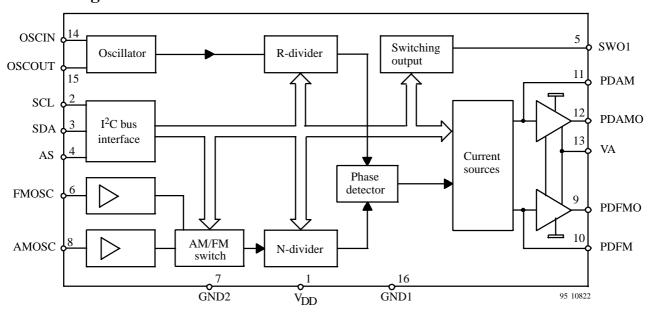
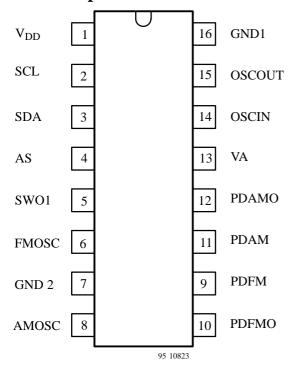


Figure 1. Block diagram

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Pin Description



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Pin	Symbol	Function
1	V _{DD}	Supply voltage
2	SCL	I ² C bus clock
3	SDA	I ² C bus data
4	AS	Address selection
5	SWO1	Switching output
6	FMOSC	FM oscillator input
7	GND 2	Ground 2 (analog)
8	AMOSC	AM oscillator input
9	PDFM	FM current output
10	PDFMO	FM analog output
11	PDAM	AM current output
12	PDAMO	AM analog output
13	VA	Analog supply voltage
14	OSCIN	Oscillator input
15	OSCOUT	Oscillator output
16	GND1	Ground 1 (digital)

Functional Description

The U4289BM is controlled via the 2-wire I²C bus. For programming there are one module address byte, two subaddress bytes and five data bytes.

The module address contains a programmable address bit A 1 which with address select input AS (Pin 4) makes it possible to operate two U4289BM in one system. If bit A 1 is identical with the status of the address select input AS, the chip is selected .

The subaddress determines which one of the data bytes is transmitted first. If subaddress of R-divider is transmitted, the sequence of the next data bytes is DB 0 (Status), DB 1 and DB 2.

If subaddress of N-divider is transmitted, the sequence of the next data bytes is DB 3 and DB 4. The bit organisation of the module address, subaddress and 5 data bytes are shown in figure 6.

Each transmission on the I²C bus begins with the "START"- condition and has to be ended by the "STOP"-condition (see figure 7).

The integrated circuit U4289BM has two separate inputs for AM and FM oscillator. Pre-amplified AM and FM signals are fed to the 16 bit N-divider via AM/FM switch. AM/FM switch is controlled by software. Tuning steps can be selected by 16 bit R-divider. Further there is a digital memory phase detector. There are two separate current sources for AM and FM amplifier (charge pump) as given in electrical characterisitics. It allows independent adjustment of gain, whereby providing high current for high speed tuning and low current for stable tuning.



Absolute Maximum Ratings

Input voltage Pins 2, 3, 4, 6, 8, 14 and Output current Pins 3 and 5 Output drain voltage Pin 5 Analog supply voltage Pin 13 with 220 Ω seriell resistance 2 minutes 1) Output current Pins 9 and 12 Ambient temperature range		Symbol	Value	Unit
Supply voltage	Pin 1	V_{DD}	−0.3 to +6	V
Input voltage	Pins 2, 3, 4, 6, 8, 14 and 15	V _I	-0.3 to $V_{DD} + 0.3$	V
Output current	Pins 3 and 5	Io	−1 to +5	mA
Output drain voltage	Pin 5	V _{OD}	15	V
Analog supply voltage with 220 Ω seriell resistance		$egin{array}{c} V_A \ V_A \end{array}$	6 to 15 24	V V
Output current	Pins 9 and 12	I_{AO}	-1 to +20	mA
Ambient temperature range		T _{amb}	-30 to +85	°C
Storage temperature range		T _{stg}	-40 to +125	°C
Junction temperature		Tj	125	°C
Electrostatic handling (mod method 3015.7: all supply p		± V _{ESD}	1000	V

¹⁾ corresponding our application circuit (page 7)

Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient	R _{thJA}	160	K/W

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Electrical Characteristics

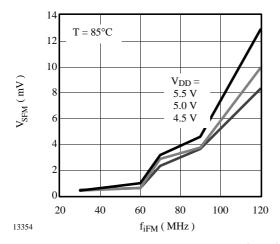
 V_{DD} = 5 V, V_{A} = 10 V, T_{amb} = 25°C, unless otherwise specified

Parameters	Test conditions	/ Pin	Symbol	Min.	Тур.	Max.	Unit
Supply voltage		Pin 1	V_{DD}	4.5	5.0	5.5	V
Quiescent supply current	AM-mode FM-mode	Pin 1	I_{DD}		4.0 4.0	7.0 7.0	mA
FM input sensitivity, R _G =	50 Ω FMOSC						
$f_i = 70 \text{ to } 120 \text{ MHz}$		Pin 6	V _{SFM}	40			mV _{rms}
$f_i = 160 \text{ MHz}$		Pin 6	V _{SFM}	150			mV _{rms}
AM input sensitivity, R _G =	50 Ω AMOSC						
$f_i = 0.6 \text{ to } 35 \text{ MHz}$		Pin 8	V _{SAM}	40			mV _{rms}
Oscillator input sensitivity	$R_{\rm G} = 50 \Omega \rm OSCIN$	١					
$f_i = 0.1 \text{ to } 15 \text{ MHz}$		Pin 14	V _{SOSC}	100			mV _{rms}
Phase detector PDFM							
Output current 1		Pin 10	± I _{PDFM}	1600	2000	2400	μΑ
Output current 2		Pin 10	± I _{PDFM}	400	500	600	μΑ
Leakage current		Pin 10	± I _{PDFML}			20	nA
Phase detector PDAM	T				1	1	
Output current 1		Pin 11	± I _{PDAM}	160	200	240	μΑ
Output current 2		Pin 11	± I _{PDAM}	40	50	60	μΑ
Leakage current	Pin 11	± I _{PDAML}			20	nA	
Analog output PDFMO, P		1.10					
Saturation voltage LOW	Pins 9 $I = 15 \text{ mA}$	V _{satL}		200	400	mV	
HIGH			V _{satH}	9.5	9.95	100	V
I ² C bus SCL, SDA, AS							
Input voltage	Pins 2	, 3 and 4	V _{iBUS}				
HIGH				3.0		V_{DD}	V
LOW		D: 2		0		1.5	V
Output voltage Acknowledge LOW	$I_{SDA} = 3 \text{ mA}$	Pin 3	V_{O}			0.4	V
Clock frequency	SDA -	Pin 2	f _{SCL}			100	kHz
Rise time SDA, SCL	Pin	s 2 and 3	t _r			1	μs
Fall time SDA, SCL		s 2 and 3	t _f			300	ns
Period of SCL		Pin 2	1				
HIGH	HIGH		t _H	4.0			μs
LOW	LOW		$t_{ m L}$	4.7			μs
Setup time					T	I	T
Start condition			t _{sSTA}	4.7			μs
Data Stop condition			t _{sDAT}	250 4.7			ns µs
Time space ¹⁾			t _{sSTOP}	7./			μο
•			t _{wSTA}	4.7			μs



Parameters	Test conditions / Pin Sym		Min.	Тур.	Max.	Unit
Hold time						
Start condition DATA		t _{hSTA} t _{hDAT}	4.0 0			μs μs

This is a space of time where the bus must be free from data transmission and before a new transmission can be started.



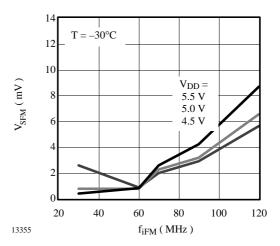
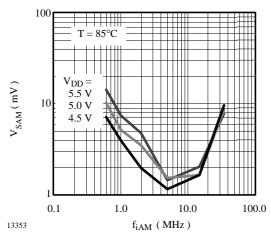


Figure 3. FM input sensitivity



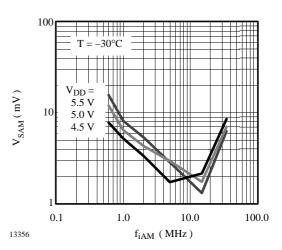


Figure 4. AM input sensitivity

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Bus Timing

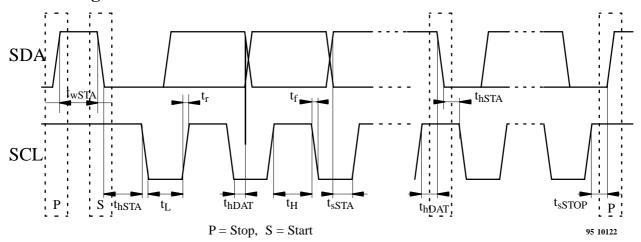


Figure 5. Bus timing





Bit Organization

		LSB		
0	0/1	0		
A2	A1	A0		
1	X	X		
1	X	X		
		LSB		
PD	PD	PD		
ANA	POL	CUR		
D2	D1	D0		
		28		
		20		
N-divider				
		20		

	LOW	HIGH
AM/FM	FM-operation	AM-operation
PD – ANA	PD analog	TEST
PD – POL	Negative polarity Positive polarity Output current 2 Output current 1	
PD – CUR		

Figure 6.

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Transmission Protocol

	MSB LSB										
S	Address A0	A	Subaddress R-divider	A	Data 0	A	Data 1	A	Data 2	A	P

	MSB	LSB								
S	Add	ress	A	Subaddress	Α	Data 3	A	Data 4	Α	P
	A7	A0		N-divider				A		

S = Start P = Stop A = Acknowledge

Figure 7.

Application Circuit

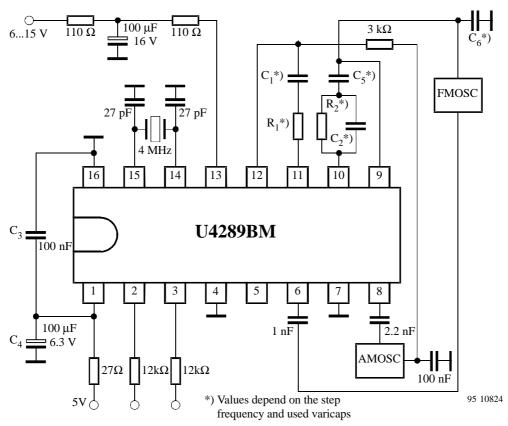


Figure 8. Application circuit



Recommendations for Applications

- $C_3 = 100 \text{ nF}$ should be very close to Pin 1 (V_{DD}) and Pin 16 (GND 1)
- GND 2 (Pin 7 analog ground) and GND 1 (Pin 16 digital ground) must be connected according to figure 8
- 4 MHz crystal must be very close to Pin 14 and Pin 15
- Components of the charge pump (C₁/R₁ for AM and C₂/R₂ for FM) should be very close to Pin 11 with respect to Pin 10.

PCB-Layout

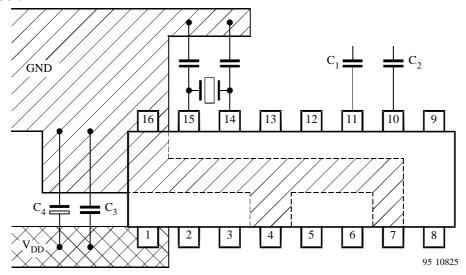
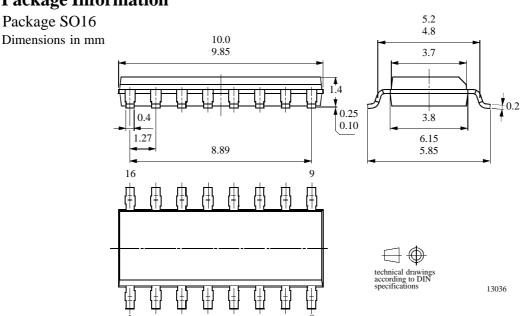


Figure 9. PCB layout

Package Information



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Ozone Depleting Substances Policy Statement

It is the policy of Atmel Germany GmbH to

- 1. Meet all present and future national and international statutory requirements.
- Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Atmel Germany GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Atmel Germany GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Atmel Wireless & Microcontrollers products for any unintended or unauthorized application, the buyer shall indemnify Atmel Wireless & Microcontrollers against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Data sheets can also be retrieved from the Internet: http://www.atmel-wm.com

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